ne<mark>x</mark>peria

Important notice

Dear Customer,

On 7 February 2017 the former NXP Standard Product business became a new company with the tradename **Nexperia**. Nexperia is an industry leading supplier of Discrete, Logic and PowerMOS semiconductors with its focus on the automotive, industrial, computing, consumer and wearable application markets

In data sheets and application notes which still contain NXP or Philips Semiconductors references, use the references to Nexperia, as shown below.

Instead of <u>http://www.nxp.com</u>, <u>http://www.philips.com/</u> or <u>http://www.semiconductors.philips.com/</u>, use <u>http://www.nexperia.com</u>

Instead of sales.addresses@www.nxp.com or sales.addresses@www.semiconductors.philips.com, use **salesaddresses@nexperia.com** (email)

Replace the copyright notice at the bottom of each page or elsewhere in the document, depending on the version, as shown below:

- © NXP N.V. (year). All rights reserved or © Koninklijke Philips Electronics N.V. (year). All rights reserved

Should be replaced with:

- © Nexperia B.V. (year). All rights reserved.

If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via **salesaddresses@nexperia.com**). Thank you for your cooperation and understanding,

Kind regards,

Team Nexperia





Product data sheet

1. Product profile

1.1 General description

NPN/PNP transistor pair connected as push-pull driver in a SOT457 (SC-74) Surface-Mounted Device (SMD) plastic package.

1.2 Features

- Switching transistors in push-pull configuration
- Application-optimized pinout
- Space-saving solution
- Internal connections to minimize layout effort
- Reduces component count

1.3 Applications

- MOSFET driver
- Power bipolar transistor driver
- Output current booster for operational amplifier

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transis	stor; for the PNP transistor	with negative pola	rity			
V _{CEO}	collector-emitter voltage	open base	-	-	40	V
I _C	collector current		-	-	0.6	А
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms	-	-	1	A



2. Pinning information

Table 2.	Pinning		
Pin	Description	Simplified outline	Symbol
1	base TR1, TR2		
2	collector TR2		
3	collector TR2	0	
4	emitter TR1, TR2		
5	collector TR1		
6	collector TR1		1 2 3 <i>006aaa659</i>

3. Ordering information

Table 3. Ordering information					
Type number	Package				
	Name	Description	Version		
PMD2001D	SC-74	plastic surface-mounted package (TSOP6); 6 leads	SOT457		

4. Marking

Table 4.	Marking codes	
Type numb	per	Marking code
PMD2001D)	9E

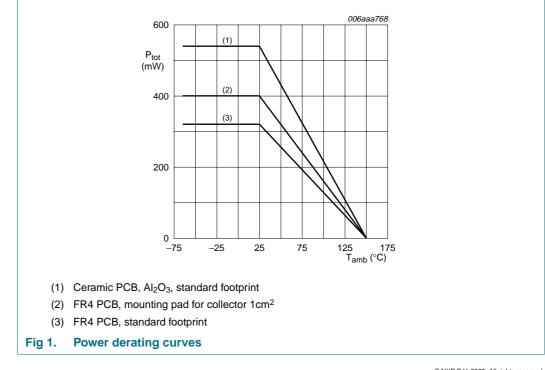
5. Limiting values

Symbol	Parameter	Conditions	Min	Max	Unit
Per transis	stor; for the PNP transistor v	with negative polari	ty		
V _{CBO}	collector-base voltage	open emitter	-	40	V
V _{CEO}	collector-emitter voltage	open base	-	40	V
I _C	collector current		-	0.6	А
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms	-	1	А
I _{BM}	peak base current		-	0.1	А
		single pulse; t _p ≤ 1 ms	-	0.2	A
Per device)				
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	[1] -	320	mW
			[2] _	400	mW
			[3] _	540	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1cm².

[3] Device mounted on a ceramic PCB, AI_2O_3 , standard footprint.



Rev. 02 - 28 August 2009

MOSFET driver

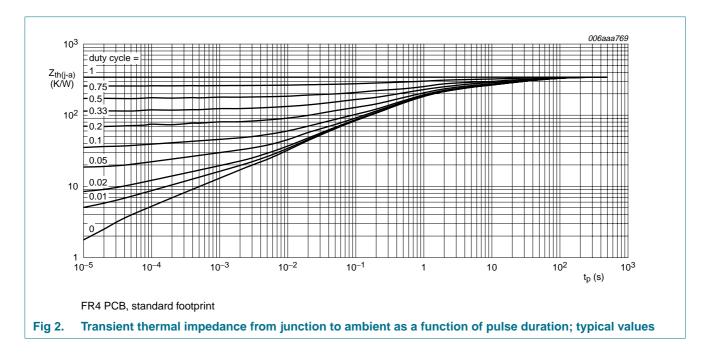
6. Thermal characteristics

Table 6.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-a)} thermal resistance from junction to ambient		in free air	<u>[1]</u> _	-	390	K/W
	junction to ambient		[2] _	-	315	K/W
			[3]	-	230	K/W

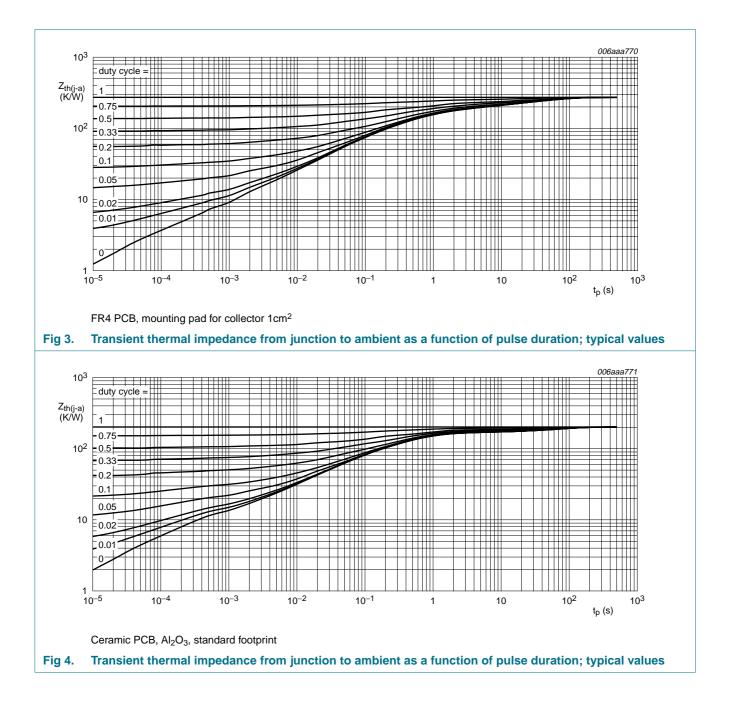
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1cm².

[3] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.







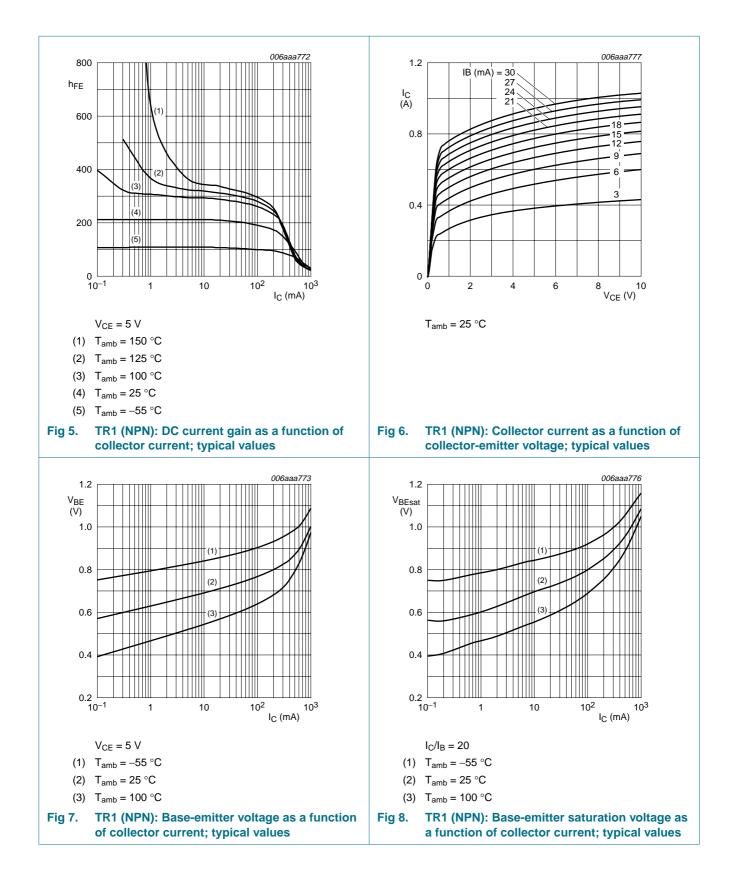
7. Characteristics

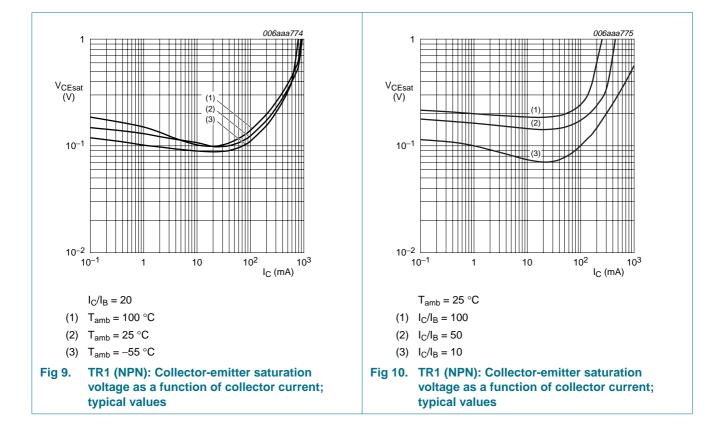
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per NPN	I transistor						
I _{CBO}	CBO collector-base cut-off current	$V_{CB} = 40 \text{ V}; \text{ I}_{E} = 0 \text{ A}$		-	-	10	nA
		$V_{CB} = 40 \text{ V}; I_E = 0 \text{ A};$ T _j = 150 °C		-	-	10	μA
h _{FE}	DC current gain	V_{CE} = 5 V; I_C = 1 mA		100	210	-	
		$V_{CE} = 5 \text{ V}; I_{C} = 200 \text{ mA}$		100	170	300	
		$V_{CE} = 5 \text{ V}; I_{C} = 500 \text{ mA}$	[1]	50	100	-	
V _{CEsat}	collector-emitter	$I_{C} = 200 \text{ mA}; I_{B} = 20 \text{ mA}$		-	150	250	mV
	saturation voltage	$I_{C} = 500 \text{ mA}; I_{B} = 50 \text{ mA}$	[1]	-	300	500	mV
V _{BEsat}	base-emitter	$I_{C} = 200 \text{ mA}; I_{B} = 20 \text{ mA}$		-	0.86	1	V
	saturation voltage	$I_{C} = 500 \text{ mA}; I_{B} = 50 \text{ mA}$	[1]	-	0.95	1.1	V
Per PNF	• transistor						
I _{CBO}		$V_{CB} = -40$ V; $I_E = 0$ A		-	-	-10	nA
current	current	$V_{CB} = -40 \text{ V}; I_E = 0 \text{ A};$ $T_j = 150 \text{ °C}$		-	-	-10	μA
h _{FE}	DC current gain	V_{CE} = -5 V; I_C = -1 mA		100	180	-	
		V_{CE} = –5 V; I_{C} = –200 mA		80	125	300	
		V_{CE} = –5 V; I_{C} = –500 mA	[1]	50	80	-	
V _{CEsat}	collector-emitter	I_C = -200 mA; I_B = -20 mA		-	-130	-250	mV
	saturation voltage	$I_C = -500 \text{ mA}; I_B = -50 \text{ mA}$	<u>[1]</u>	-	-280	-500	mV
V _{BEsat}	base-emitter	$I_C = -200 \text{ mA}; I_B = -20 \text{ mA}$		-	-0.87	-1	V
	saturation voltage	$I_C = -500 \text{ mA}; I_B = -50 \text{ mA}$	<u>[1]</u>	-	-0.98	-1.1	V
Per dev	ice						
t _d	delay time	$I_{C} = 0.15 \text{ A}; V_{I} = 7.5 \text{ V}$		-	3	-	ns
t _r	rise time			-	3	-	ns
t _{on}	turn-on time			-	6	-	ns
t _s	storage time			-	2	-	ns
t _f	fall time			-	3	-	ns
t _{off}	turn-off time			-	5	-	ns

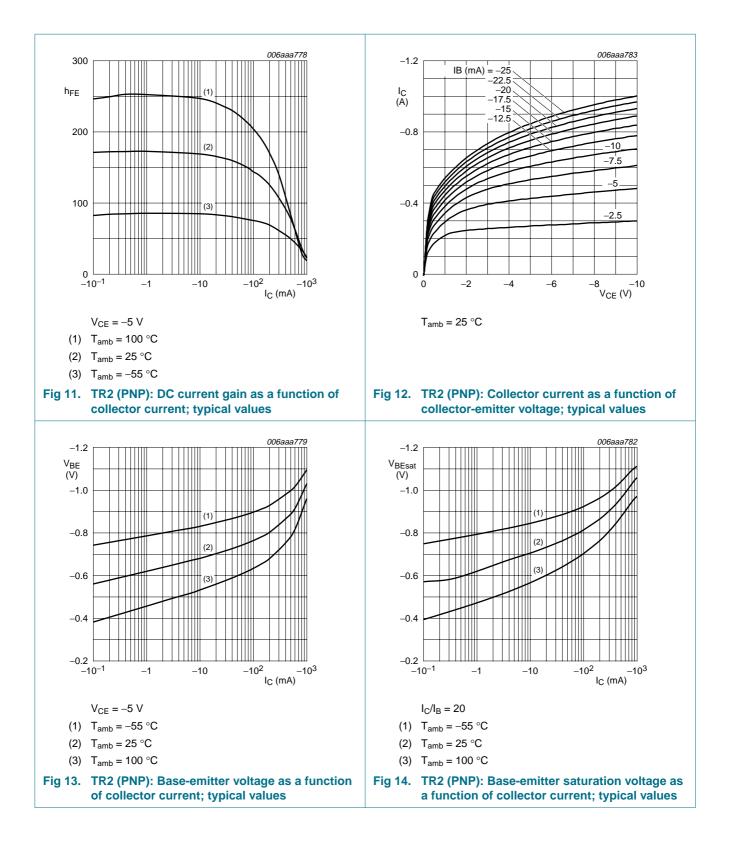
[1] Pulse test: $t_p \leq 300 \ \mu s; \ \delta \leq 0.02$

NXP Semiconductors

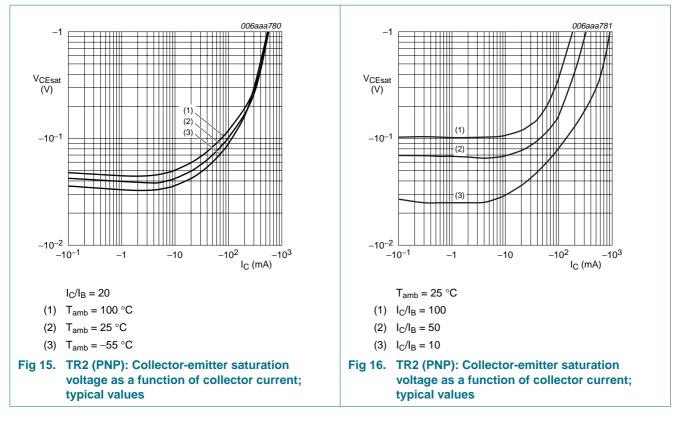
PMD2001D MOSFET driver



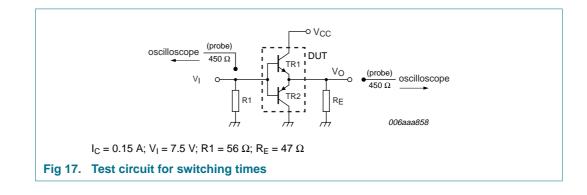




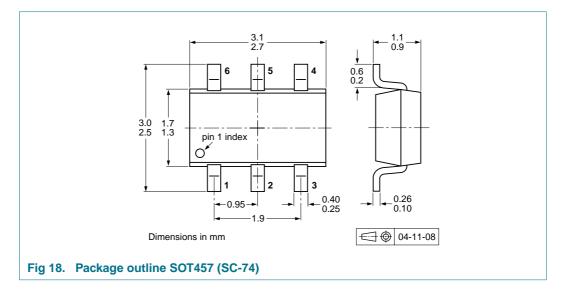
PMD2001D_2 Product data sheet



8. Test information



9. Package outline



10. Packing information

Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

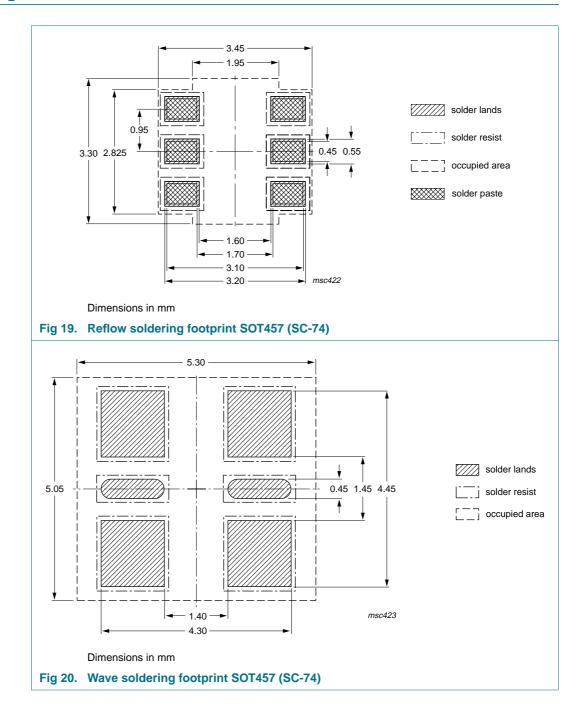
Type number	Package	Description	Packing	g quantity
			3000	10000
PMD2001D SOT4	SOT457	4 mm pitch, 8 mm tape and reel; T1	^[2] -115	-135
		4 mm pitch, 8 mm tape and reel; T2	<u>3</u> -125	-165

[1] For further information and the availability of packing methods, see <u>Section 14</u>.

[2] T1: normal taping

[3] T2: reverse taping

11. Soldering



12. Revision history

Table 9. Revisio	n history			
Document ID	Release date	Data sheet status	Change notice	Supersedes
PMD2001D_2	20090828	Product data sheet	-	PMD2001D_1
Modifications:		neet was changed to reflect w legal definitions and dis		
	 Figure 20 "V 	Vave soldering footprint So	<u> </u>	d
PMD2001D_1	20060925	Product data sheet	-	-

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

13.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

13.3 Disclaimers

General — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in medical, military, aircraft, space or life support equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors accepts no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) may cause permanent damage to the device. Limiting values are stress ratings only and operation of the device at these or any other conditions above those given in the Characteristics sections of this document is not implied. Exposure to limiting values for extended periods may affect device reliability.

Terms and conditions of sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nxp.com/profile/terms, including those pertaining to warranty, intellectual property rights infringement and limitation of liability, unless explicitly otherwise agreed to in writing by NXP Semiconductors. In case of any inconsistency or conflict between information in this document and such terms and conditions, the latter will prevail.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from national authorities.

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

13.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

14. Contact information

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: salesaddresses@nxp.com

PMD2001D_2 Product data sheet

15. Contents

1	Product profile 1
1.1	General description
1.2	Features
1.3	Applications 1
1.4	Quick reference data 1
2	Pinning information 2
3	Ordering information 2
4	Marking
5	Limiting values 3
6	Thermal characteristics 4
7	Characteristics
8	Test information 10
9	Package outline 11
10	Packing information 11
11	Soldering 12
12	Revision history 13
13	Legal information 14
13.1	Data sheet status 14
13.2	Definitions 14
13.3	Disclaimers 14
13.4	Trademarks 14
14	Contact information 14
15	Contents 15



Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

© NXP B.V. 2009.

All rights reserved.

For more information, please visit: http://www.nxp.com For sales office addresses, please send an email to: salesaddresses@nxp.com

Date of release: 28 August 2009 Document identifier: PMD2001D_2



单击下面可查看定价,库存,交付和生命周期等信息

>>Nexperia(安世)